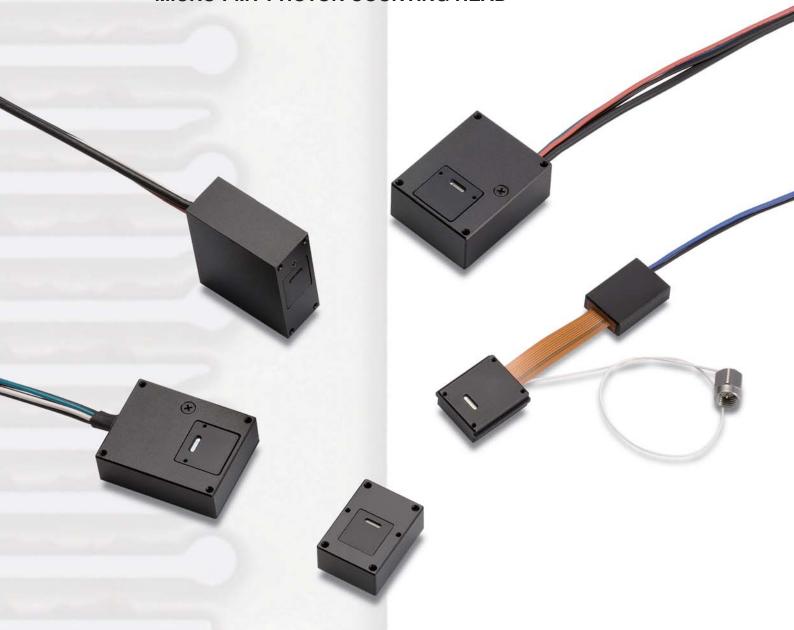
Micro PIVIT® HAMAMATSU

MICRO PMT ASSEMBLY
MICRO PMT MODULES
MICRO PMT PHOTON COUNTING HEAD



HAMAMATSU

PHOTON IS OUR BUSINESS

World's smallest and lightest photomultiplier tube* Micro PMT™

* By our research (as of December 2015)

Easy to mass produce

Micro PMT can be produced in high volume while still maintaining high reliability and performance. What makes this possible is overall integrated usage of our in-house advanced technologies for MEMS (micro-electro-mechanical systems), semiconductor manufacturing, electron trajectory design, vacuum sealed packaging, and vacuum processing.

Tiny dimensions

Micro PMT has a three-layer structure where a silicon substrate is sandwiched between two glass substrates. Utilizing only three components gives tiny dimensions impossible up until now.

High shock resistance

Micro PMT devices offer strong shock resistance since anodic bonding by MEMS technology is utilized to join the silicon substrate to the glass substrates. This high cushioning or shock resistance makes them ideal for developing high-performance, hand-held testing and analysis devices.

Customizing support

Feel free to consult with us on customizing to match customer usage conditions and environments.

High sensitivity and fast response

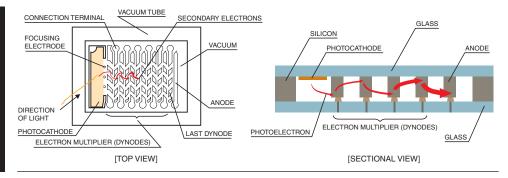
Micro PMT utilizes the same high precision structure for electrode arrangement as conventional PMTs and so provides the high sensitivity and fast response needed from a PMT.

Full-scale Micro PMT image!



Micro PMT works on the same vacuum tube technology and principle as conventional PMTs and so can deliver the same performance as conventional PMT yet in a compact and light-weight unit.

Micro PMT internal structure



What is a PMT (photomultiplier tube)?

The PMT is a photosensor delivering superb high sensitivity and response speed compared with other types of photosensors. The PMT makes use of the secondary emission effect for electron multiplication and so achieves extremely high sensitivity and low noise compared to other photosensors currently in use to measure UV light, visible light, and near-infrared light. These features allow the PMT to be used in a broad range of applications including high-performance medical equipment and environmental monitors, etc.



could prove ideal not only for early stage disease diagnosis but also daily health care management.



Measurements under various environments and any type of location

Micro PMT also proves ideal as a photosensor for environmental monitoring tasks. Environmental problems including abnormal weather phenomenon and widescale natural disasters are recently occurring at places all around the world. If compact measurement devices were readily available, then environmental phenomena could be quickly detected at diverse locations to keep damage and losses to a be minimum.

PMT® PRODUCT CONFIGURATION

	Assembly type	Module type					
Basic configration	Micro PMT + Micro PMT + Divider circuit + High voltage power supply Divider circuit						
Additional function		Current output		Voltage output	Photon counting		
Appearance	H12400	H14066	H12402/H12403	H12404/H12405	H12406		
	series	series	series	series	series		
Spectral response (nm)	300 to 650 300 to 850 300 to 920	300 to 650 300 to 850	300 to 650 300 to 850 300 to 920	300 to 650 300 to 850 300 to 920	300 to 650 300 to 850 300 to 920		

MICRO PMT ASSEMBLY H12400 SERIES

The H12400 series is a high sensitivity photosensor that combines a Micro PMT with a voltage divider circuit. The H12400 series can be installed even in narrow spaces due to its small size.



PRODUCT VARIATIONS

Type No.	Spectral response	Photocathode material	Features
H12400-00-01	300 nm to 650 nm	Bialkali	for visible range
H12400-01-01	300 nm to 850 nm	Multialkali	for visible to near IR range
H12400-20-01	300 nm to 920 nm	Extended red multialkali	for visible to near IR range

SPECIFICATIONS

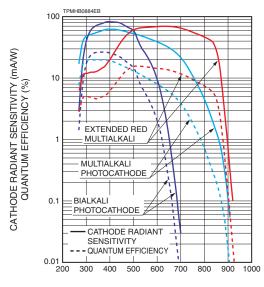
(at +25 °C)

							(at 120 0
	Parameter			H12400-00-01	H12400-01-01	H12400-20-01	Unit
Peak sensi	Peak sensitivity wavelength			420 630			nm
Window ma	aterial				$3(X) \times 1(Y)$		mm
Effective ar	ea				Borosilicate glass		_
Dynode nu	mber of stages				12		_
Maximum	Supply voltage	Between anode and ca	athode		-1150		V
	Divider current	current			126		μA
ratings	Average output s	signal current			5	300 400 — 0.45 60 30	μA
	Luminous consit	is sites s	Min.	50	100	300	μ A /lm
	Luminous sensit	ivity	Тур.	80	200	400	μΑ/ΙΙΙΙ
Cathode	Blue sensitivity in	ndex (CS 5-58)	Тур.	8.0	_	_	_
	Red / White ratio)	Тур.	_	0.2	0.45	_
	Radiant sensitivity ①		Тур.	80	62	60	mA/W
	Luminaua aanait	i:	Min.	30	15	30	A/lm
	Luminous sensit	ivity	Тур.	160	70	30	Avim
	Radiant sensitivi	ty ^①	Тур.	1.6 × 10 ⁵	2.1 × 10 ⁴	1.5 × 10 ⁴	A/W
Anode ^②	Dark current ³		Тур.	0.3 0.6		0.6	^
	Dark current		Max.		3	6	nA
		Rise time	Тур.		1.2		
	Time response	Transit time	Тур.		8.0		ns
	T.T.S. ⁽⁴⁾		Тур.		1.3		7
Gain ^②	Gain ^② Typ.		2.0 × 10 ⁶	3.5 × 10⁵	2.5 × 10 ⁵		
Operating a	Operating ambient temperature ®		+5 to +50			°C	
Storage ter	nperature ^⑤				-20 to +50		
Weight					11		g

①Measured at the peak sensitivity wavelength

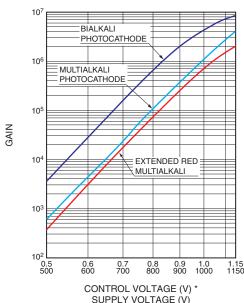
5No condensation

SPECTRAL RESPONSE



WAVELENGTH (nm)

GAIN



SUPPLY VOLTAGE (V)

②Supply Voltage: -900 V

③After 30 minutes storage in darkness

⁴T.T.S.=Transit Time Spread (FWHM)

H14066 SERIES

The H14066 series is a high sensitivity photosensor module that contain a Micro PMT, a voltage divider circuit, and a high-voltage power supply circuit. This module pin output type can board mounting, which can be easily operated with a low voltage supply.



PRODUCT VARIATIONS

Type No.	Spectral response	Photocathode material	Features
H14066	300 nm to 650 nm	Bialkali	for visible range
H14066-01	300 nm to 850 nm	Multialkali	for visible to near IR range

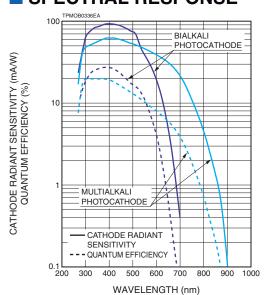
SPECIFICATIONS

(at +25 °C)

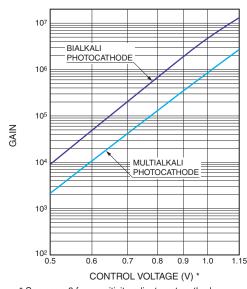
					(at +25 C
	Parameter		H14066	H14066-01	Unit
Peak sensitivity wavelength			420		nm
Effective ar	ea		4(X) ×	1(Y)	mm
Window ma	aterial		Borosilicat	te glass	
Dynode nu	mber of stages		10		
Input voltag	ge		+4.75 to	+5.25	V
Maximum i	nput voltage		+5.5	5	V
Maximum i	nput current ^①		5		mA
Maximum a	average output signal current		5		μA
Maximum o	control voltage		+1.1	5	V
Recommer	nded control voltage adjustment range		+0.5 to +1.0	+0.5 to +1.1	V
Control vol	tage input impedance		1		MΩ
Luminous sensitivity	Luminous sensitivity	Min.	70	100	μA/lm
		Typ.	100	200	μΑνιιτι
Cathode	Blue sensitivity index (CS 5-58)	Typ.	11.5	_	
	Red / White ratio	Typ.	_	0.2	
	Radiant sensitivity ^②	Typ.	93	62	mA/W
	Luminous sensitivity ^③	Min.	30	15	A/Im
	Luminous sensitivity	Typ.	200	70	AVIIII
Anode ^②	Radiant sensitivity ^{②③}	Typ.	1.9 × 10⁵	2.2×10^{4}	A/W
Alloue	Dark current 34	Typ.	0.3	}	nA
	Dark current	Max.	3		IIA
	Time response Rise time	Typ.	1.2		ns
Gain		Typ.	2.0×10^{6}	3.5×10^{5}	
	e ³⁾⁵ (peak to peak)	Max.	0.3	}	mV
Settling tim	e [®]	Max.	10		S
Operating a	ambient temperature ^⑦		+5 to +50		°C
Storage ter	mperature ^⑦		-20 to +50		°C
Weight			10		g

①At +5 V input voltage, +0.9 V control voltage, and output current equal to dark current

SPECTRAL RESPONSE



GAIN



②Measured at the peak sensitivity wavelength

③+0.9 V control voltage ④After 30 minutes storage in darkness.

 $[\]odot$ Cable RG-174/U, Cable length 450 mm, Load resistance=1 M Ω , Load capacitance=22 pF

[®]The time required for the output to reach a stable level following a change in the control voltage from +1.0 V to + 0.5 V.

No condensation

MICRO PMT MODULE H12402/H12403 **SERIES**

The H12402/H12403 series are high sensitivity photosensor modules that contain a Micro PMT, a voltage divider circuit, and a high-voltage power supply circuit. These modules can be easily operated with a low voltage supply.



▲Left: H12403 series Right: H12402 series

PRODUCT VARIATIONS

Type No.	Spectral response	Photocathode material	Features
H12402 / H12403	300 nm to 650 nm	Bialkali	for visible range
H12402-01 / H12403-01	300 nm to 850 nm	Multialkali	for visible to near IR range
H12402-20 / H12403-20	300 nm to 920 nm	Extended red multialkali	for visible to near IR range

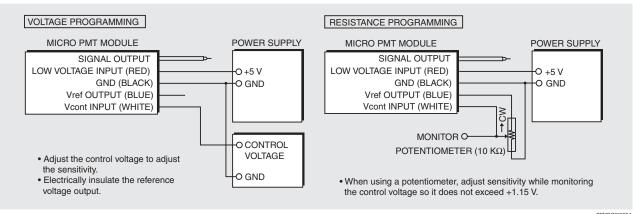
SPECIFICATIONS

(at +25 °C)

	Parameter		H12402 / H12403	H12402-01 / H12403-01	H12402-20 / H12403-20	Unit
Peak sensi	tivity wavelength		4	120	630	nm
Effective ar	rea			3(X) × 1(Y)	1	mm
Window ma	aterial			Borosilicate glass		_
Dynode nu	mber of stages			12		_
Input voltag	ge			+4.5 to +5.5		V
Maximum i	nput voltage			+5.5		V
Maximum i	nput current ^①			20		mA
Maximum a	average output signal current ^②			5		μA
Maximum o	control voltage			+1.15		V
Recommer	nded control voltage adjustment	range	+0.5 to +1.0	+0.5 t	o +1.1	V
Control vol	tage input impedance			1		ΜΩ
	Luminous sensitivity	Min.	50	100	300	μ A /lm
		Тур.	80	200	400	
Cathode	Blue sensitivity index (CS 5-58)	Тур.	8.0	_	_	_
	Red / White ratio	Тур.	_	0.2	0.45	_
	Radiant sensitivity [®]	Тур.	80	62	60	mA/W
	Luminous sensitivity	Min.	30	15	30	A/lm
	Laminous sensitivity	Тур.	160	70	100	
Anode ^②	Radiant sensitivity [®]	Тур.	1.6 × 10⁵	2.1 × 10 ⁴	1.5 × 10 ⁴	A/W
7111000	Dark current ⁴	Тур.		0.3	0.6	nA
	Bank darrent	Max.		3	6	1171
	Time response Rise time	Тур.	1.2			ns
Gain ^②		Тур.	2.0 × 10 ⁶	3.5 × 10⁵	2.5 × 10 ⁵	
	se ^{②⑤} (peak to peak)	Max.		0.3		mV
Settling tim		Max.	10			s
Operating a	ambient temperature ^⑦		+5 to +50			°C
Storage ter	mperature ^⑦		-20 to +50			°C
Weight		Тур.	42 (H	12402 series), 52 (H12403	3 series)	g

- ①At +5 V input voltage, +0.9 V control voltage, and output current equal to dark current
- 2+0.9 V control voltage
- 3 Measured at the peak sensitivity wavelength
- 4 After 30 minutes storage in darkness.
- $\bar{\mbox{5}}$ Cable RG-174/U, Cable length 450 mm, Load resistance=1 M Ω , Load capacitance=22 pF
- ®The time required for the output to reach a stable level following a change in the control voltage from +1.0 V to + 0.5 V.
- No condensation

SENSITIVITY ADJUSTMENT METHOD



^{*} See page 4 for spectral response and gain.

H12404/H12405 SERIES

The H12404/H12405 series are high sensitivity photosensor modules that contain a Micro PMT, a voltage divider circuit, and a high-voltage power supply circuit and amplifier circuit. These modules can be easily operated with a low voltage supply.



▲Left: H12405 series Right: H12404 series

PRODUCT VARIATIONS

Type No.	Spectral response	Photocathode material	Features
H12404 / H12405	300 nm to 650 nm	Bialkali	for visible range
H12404-01 / H12405-01	300 nm to 850 nm	Multialkali	for visible to near IR range
H12404-20 / H12405-20	300 nm to 920 nm	Extended red multialkali	for visible to near IR range

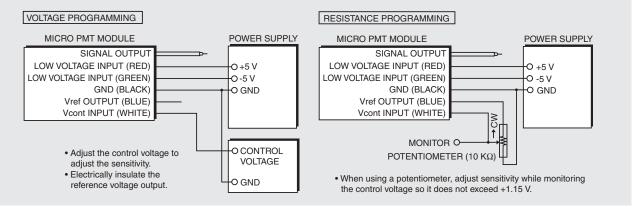
SPECIFICATIONS

(at +25 °C)

	Parameter		H12404 / H12405	H12404-01 / H12405-01	H12404-20 / H12405-20	Unit
Peak sensi	itivity wavelength		4	20	630	nm
Effective a	rea	3(X) × 1(Y)				mm
Window ma	aterial			Borosilicate glass		_
Dynode nu	mber of stages			12		_
Input voltag	ge			±4.5 to ±5.5		V
Maximum i	input voltage			±5.5		V
Maximum i	input current ^①			+23.5 / -3.5		mA
Maximum a	average output signal current		-	+4 (Load resistance 10 kg	2)	V
	control voltage			+1.15		V
Recommer	nded control voltage adjustment	range	+0.5 to +1.0	+0.5 t	0 +1.1	V
Control vol	tage input impedance			1		MΩ
	Luminous sensitivity	Min.	50	100	300	μA/lm
	•	Тур.	80	200	400	μ, γ
Cathode	Blue sensitivity index (CS 5-58)	Тур.	8.0	_	_	
	Red / White ratio	Тур.	_	0.2	0.45	
	Radiant sensitivity ^②	Тур.	80	62	60	mA/W
	Luminous sensitivity ^③	Min.	3.0×10^{7}	1.5×10^7	3.0×10^7	V/lm
	,	Тур.	1.6 × 10 ⁸	7.0×10^{7}	1.0 × 10 ⁸	
Anode ^②	Radiant sensitivity 23	Тур.	160	21	15	V/nW
	Voltage output depending	Тур.).3	0.6	mV
	on PMT dark current 34	Max.		3	6	
PMT gain		Тур.	2.0 × 10 ⁶	3.5 × 10⁵	2.5 × 10 ⁵	_
Frequency			DC to 20 kHz			
	voltage conversion factor			1		V/µA
Output offset voltage Typ.		±1			mV	
Ripple noise ³⁵ (peak to peak) Max.		1.5			mV	
Settling time [®] Max.		10			S	
	ambient temperature ®		+5 to +50			°C
	mperature ^⑦			-20 to +50		°C g
Weight			44 (H12404 series), 54 (H12405 series)			

①At ±5 V input voltage, +0.9 V control voltage, and output current equal to dark current ②Measured at the

SENSITIVITY ADJUSTMENT METHOD



^{*} See page 4 for spectral response and gain.

②Measured at the peak sensitivity wavelength

③+0.9 V control voltage ④After 30 minutes storage in darkness.

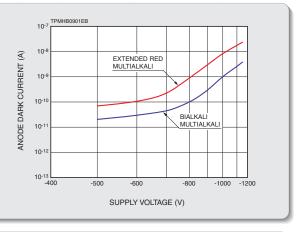
 $[\]odot$ Cable RG-174/U, Cable length 450 mm, Load resistance=1 M Ω , Load capacitance=22 pF

⁽a) The time required for the output to reach a stable level following a change in the control voltage from +1.0 V to + 0.5 V.

Characteristics

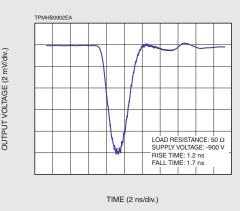
Dark current

A small amount of current is output from a photomultiplier tube even when operated in a completely dark state. This output current is called the anode dark current, and the resulting noise is a critical factor in determining the lower detection limit of photomultiplier tubes. The graph on the right shows typical dark current of a Micro PMT versus the supply voltage.



Output waveform

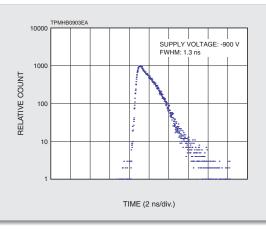
Photomultiplier tubes are photosensors with extremely high speeds. The figure on the right shows an output waveform example of a Micro PMT operating at an anodeto-cathode voltage of -900 V, measured with pulsed light (pulse width: 70 ps) that is sufficiently shorter than the response time of the PMT. This anode output pulse has a rise time of 1.2 ns and a fall time of 1.7 ns.



■ T.T.S. (transit time spread)

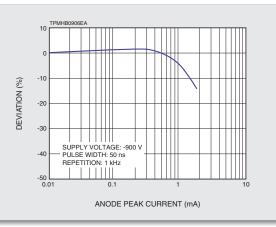
The time interval between the arrival of light at the photocathode and the instant when the anode output pulse reaches its peak amplitude is called the electron transit time.

The T.T.S. (transit time spread) indicates the fluctuations of the electron transit time measured when the photocathode is fully illuminated with single photons, and is defined as the FWHM of the histogram of the fluctuations. A typical T.T.S. of Micro PMT is 1.3 ns.



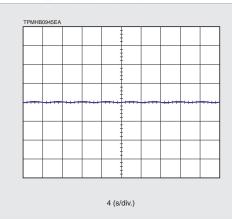
Pulse linearity

When an intense light pulse enters the photocathode of a photomultiplier tube, a large current flows in the latter dynode stages and increases the space charge density, causing current saturation. This causes the anode output to deviate from the ideal linearity. The figure below is a typical linearity of a Micro PMT versus light pulse, showing a deviation of approximately 5 % at an anode peak current of 1 mA.



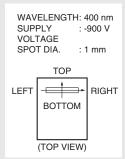
Ripple noise

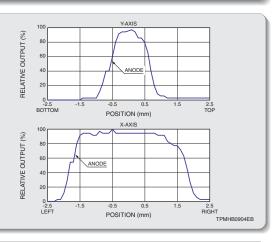
The oscillator circuit used in high-voltage power supplies in photomultiplier tube modules induces noise into the signal input due to oscillation. This induction noise is referred to as ripple. The ripple can be observed on an oscilloscope along the baseline in a low voltage range by feeding the output signal to the oscilloscope input while no light is incident on the modules. For example, under conditions where the load resistance is 1 $\mbox{M}\Omega$ and the load capacitance is 22 pF, you will see a signal with an output near 200 V and a frequency of approximately 220 kHz.



Uniformity

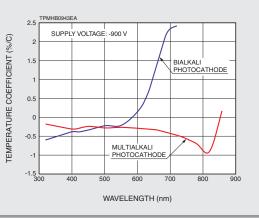
This uniformity is the variation of sensitivity with respect to the incident light position on the photocathode. The figure on the right shows an example of anode output measured by scanning a light spot of 1 mm diameter at 400 nm wavelength over the photocathode surface of a Micro PMT at a pitch of 0.1 mm in the X-axis and Y-axis directions. The output indicates relatively good uniformity.





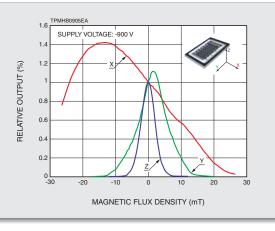
■ Temperature characteristics

The anode sensitivity of photomultiplier tubes is affected by the ambient temperature. Temperature characteristics for anode sensitivity are wavelength-dependent, and the temperature coefficient generally fluctuates from a negative value to a positive value near the long wavelength limit. The figure on the right shows temperature coefficient data of micro PMT with a bialkali photocathode and multialkali photocathode as a function of wavelength. The temperature coefficient for both photocathodes is approximately -0.3 %/C at a wavelength around 500 nm.



Magnetic characteristics

An external magnetic field deviates the photoelectrons traveling in a photomultiplier tube from their normal trajectories, causing a loss of gain. The extent of the loss of gain depends on the direction of the magnetic field. The figure on the right shows how magnetic fields affect the output of a Micro PMT. It is seen that the magnetic field in the Z direction most affects the output. Terrestrial magnetism which is less than 0.1 mT will have almost no effect on the output.



MICRO PMT PHOTON COUNTING HEAD

H12406 SERIES

The H12406 series is a photon counting head that contain a Micro PMT, a high-voltage power supply circuit and a photon counting circuit.

This photon counting head can be easily operated with a low voltage supply.



PRODUCT VARIATIONS

Type No.	Spectral response	Photocathode material	Features
H12406	300 nm to 650 nm	Bialkali	for visible range
H12406-01	300 nm to 850 nm	Multialkali	for visible to near IR range
H12406-20	300 nm to 920 nm	Extended red multialkali	for visible to near IR range

SPECIFICATIONS

(at +25 °C)

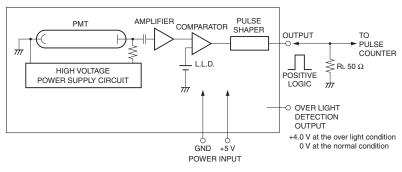
Parameter			H12406	H12406-01	H12406-20	Unit
Peak sensitivity wavelength		420 630			nm	
Effective area			$3(X) \times 1(Y)$		mm	
Window material				Borosilicate glass		_
Dynode number of	stages			12		_
Input voltage				+4.75 to +5.25		V
Max. Input voltage				+6		V
Max. Input current				40		mA
		300 nm	1.7 × 10⁵	2.1 × 10⁵	5.3×10^{4}	
	400 nm	3.6 × 10⁵	2.7 × 10 ⁵	8.8×10^{4}		
		500 nm	2.6 × 10⁵	2.3 × 10 ⁵	2.7×10^{5}	
Count sensitivity	Тур.	600 nm	4.3 × 10 ⁴	1.7 × 10 ⁵	3.0×10^{5}	s-1·pW-1
		700 nm	1.4×10^{2}	9.6 × 10 ⁴	2.9×10^{5}	
		800 nm	_	2.1 × 10 ⁴	2.1×10^{5}	
		900 nm	_	_	3.9×10^{3}	
Count linearity ①			5.0 × 10 ⁶			S ⁻¹
Dark count ^②		Тур.	10	100	500	S ⁻¹
Dark Count		Max.	50	500	2500	S-1
Pulse-pair resolutio	n		20			ns
Output pulse width			10			ns
Output pulse height		Min.	+2.0			_ v
(at load resistance	50 Ω)	Тур.		v		
Recommended load	d resistance		50			Ω
Signal output logic		Positive logic			_	
Excessive light	Excessive light incident	Min.	+3.5			V
detection output ^③ Normally Max.		+0.5			V	
Operating ambient	temperature ^④		+5 to +50			°C
Storage temperatur	re ⁴			-20 to +50		°C
Weight				46		g

①Random pulse, at 10% count loss

COUNT SENSITIVITY

106 H12406-20 H12406-20 103 200 300 400 500 600 700 800 900 1000 WAVELENGTH (nm)

BLOCK DIAGRAM



TPMOC0226EC

②After 30 minute storage in darkness

³ Load resistance 10 kg

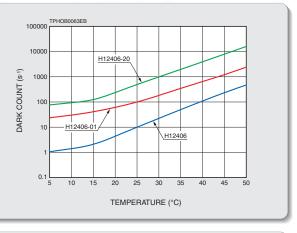
⁴No condensation

Characteristics

OUTPUT PULSE HEIGHT (1 V/div.)

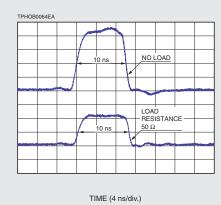
Dark count

Some dark current pulses are generated in a photomultiplier tube during operation even if no light is incident on it. These dark current pulses are amplified by an amplifier and then only those dark pulses with a height exceeding a certain discriminator threshold are output through a pulse shaper. This output, expressed in counts per second (s-1), is the dark count and indicates the lower limit of signal detection.



Output waveform

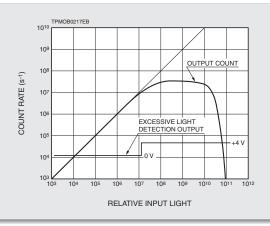
Output waveforms are positive logic signals. The figure on the right shows output waveforms measured with and without a load resistance of 50 $\Omega.$ Since photon counting head handles high-speed signals, a 50 Ω impedance cable is usually connected between a photon counting head and external device, and the input impedance of the external device should also preferably be 50 $\Omega.$



Count linearity and excessive light detection characteristics

In a random light input event, when the light level increases and exceeds a certain level, the output pulses begin to overlap each other and the count value is no longer proportional to the light level. As the light level further increases causing more pulses to overlap, the number of output pulses gradually saturates and then begins to decrease and eventually reaches 0. Count linearity is specified as the count value at which a 10 % loss occurs in the counted value compared to the theoretical value.

If the incident light level largely exceeds the count linearity, a signal (4.0 V) is output to indicate an excessive light input.



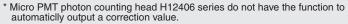
Count rate correction

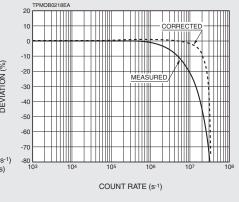
When the number of pulses measured by photon counting exceeds 10⁶ s⁻¹, counting errors begin to occur due to pulse overlap. One method for improving the count linearity utilizes a correction formula to find the approximate values. The graph on the right shows improved count linearity characteristics obtained by using a correction formula to find the approximate values.

Linearity correction formula

 $N = \frac{M}{1-Mt}$ N: real M: mea

N: real count rate (s-1)
M: measured count rate (s-1)
t: pulse pair-resolution (s)

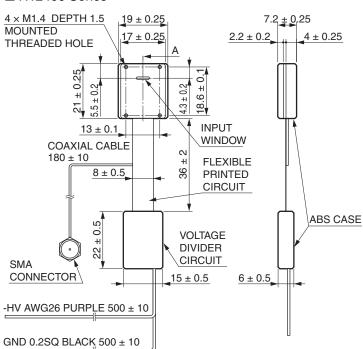


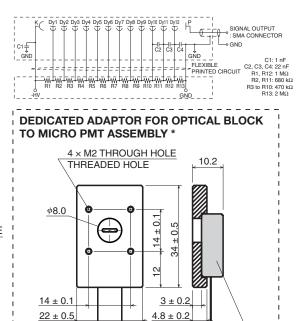


■ DIMENSIONAL OUTLINES (Unit: mm)

MICRO PMT ASSEMBLY

■ H12400 Series





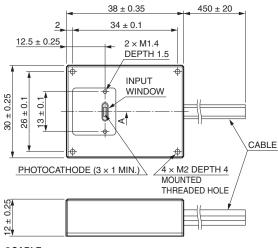
* Dedicated Adaptor for optical block is supplied.

MICRO PMT ASSEMBLY

TPMHA0590EC

MICRO PMT MODULE

■ H12402 Series



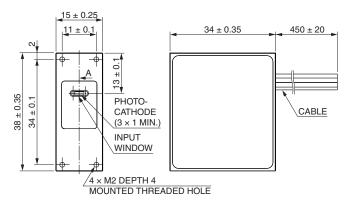
LOW VOLTAGE INPUT (+5 V): UL1430 AWG26 (RED) : UL1430 AWG26 (BLACK) Vref OUTPUT (+1.2 V) : UL1430 AWG26 (BLUE) : UL1430 AWG26 (WHITE) Vcont INPUT

No suffix (+0.5 V to +1.0 V) -01, -20 (+0.5 V to +1.1 V)

SIGNAL OUTPUT : RG-174/U Weight: 42 g

MICRO PMT MODULE

■ H12403 Series



●CABLE

LOW VOLTAGE INPUT (+5 V): UL1430 AWG26 (RED) : UL1430 AWG26 (BLACK) : UL1430 AWG26 (BLUE) Vref OUTPUT (+1.2 V) Vcont INPUT : UL1430 AWG26 (WHITE)

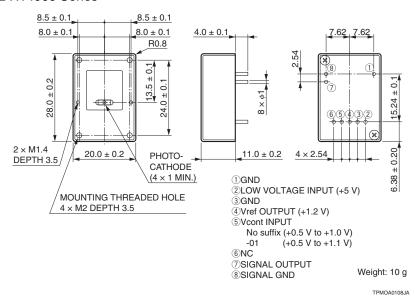
No suffix (+0.5 V to +1.0 V) -01, -20 (+0.5 V to +1.1 V) SIGNAL OUTPUT

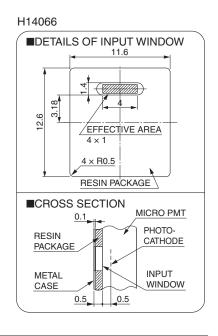
: RG-174/U Weight: 52 g

TPMOA0084ED

MICRO PMT MODULE

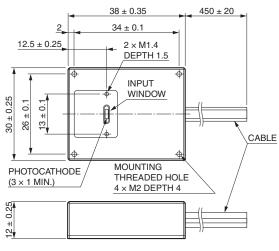
■ H14066 Series





MICRO PMT MODULE

■ H12404 Series



LOW VOLTAGE INPUT (+5 V): UL1430 AWG26 (RED) LOW VOLTAGE INPUT (-5 V) : UL1430 AWG26 (GREEN) GND : UL1430 AWG26 (BLACK)

Vref OUTPUT (+1.2 V) : UL1430 AWG26 (BLUE) Vcont INPUT : UL1430 AWG26 (WHITE)

No suffix (+0.5 V to +1.0 V)

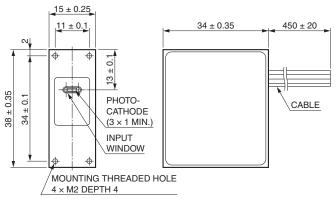
-01, -20 (-0.5 V to +1.1 V) SIGNAL OUTPUT

: RG-174/U

Weight: 44 g TPMOA0109JA

MICRO PMT MODULE

■ H12405 Series



LOW VOLTAGE INPUT (+5 V): UL1430 AWG26 (RED) LOW VOLTAGE INPUT (-5 V): UL1430 AWG26 (GREEN) : UL1430 AWG26 (BLACK) Vref OUTPUT (+1.2 V) : UL1430 AWG26 (BLUE) Vcont INPUT : UL1430 AWG26 (WHITE)

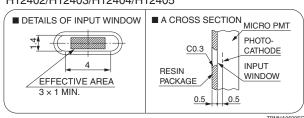
No suffix (+0.5 V to +1.0 V)

-01, -20 (-0.5 V to +1.1 V) SIGNAL OUTPUT

: RG-174/U Weight: 54 g

TPMOA0110JA

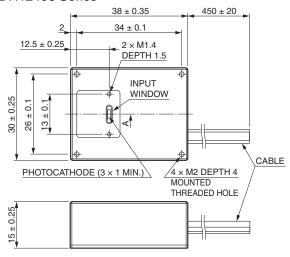
H12402/H12403/H12404/H12405



■ DIMENSIONAL OUTLINES (Unit: mm)

MICRO PMT PHOTON COUNTING HEAD

■ H12406 Series



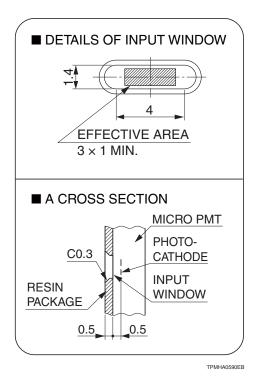
●CABLE

LOW VOLTAGE INPUT (+5 V)

: UL1430 AWG26 (RED) UL1430 AWG26 (BLACK)

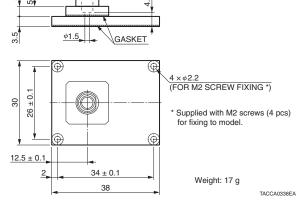
OVER LIGHT DETECTION OUTPUT: UL1430 AWG26 (BLUE) SIGNAL OUTPUT

: RG-174/U Weight: 46 g

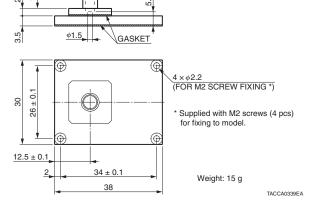


OPTION: OPTIONAL FIBER ADAPTER (sold separately)

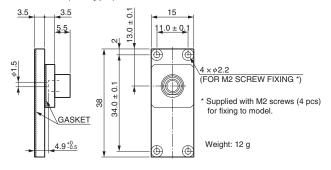
● E13561 (FC type)



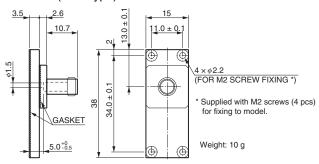
● E13562 (SMA type)



● E13563 (FC type)



E13564 (SMA type)



^{*} E13561 and E13562 are the exclusive options for H12402/H12404/H12406 series. E13563 and E13564 are the exclusive options for H12403/H12405 series.

Related Products



HIGH VOLTAGE POWER SUPPLY C14210-14 0.4 W output 1100 V / 0.4 mA

The C14210-14 is the world's smallest surface-mount high voltage power supply module with a stabilizing circuit for photomultiplier tubes.

That is suitable for operating a H12400 series, which can reflow mounting.

Parameter		Value	Unit
Input voltage range (VDD)		+3.0 to +5.0	V
Input current ^①	Max.	270	mA
Specification guaranteed output voltage r	ange	-200 to -1100	V
Output current	Max.	0.4	mA
Output voltage rise time ^②		150	ms
Line regulation	Тур.	±0.01	%
Load regulation	Тур.	±0.01	%
Temperature coefficient	Тур.	±0.01	%/°C
Ripple / Noise (p-p) [®]	Тур.	50	mV
Operating ambient temperature ^⑤		0 to +50	°C
Weight		4	g
Dimensions (W × H × D)		15 × 7 × 15	mm
Destruction for all and		Short circuit in output / Continuous overloading /	
Protective functions		Excessive controlling voltage input	

- 1): VDD=+3 V, at maximum output voltage and current
- ②: Rise time (0 %→99 %)
- 3: 5 kHz or more
- (a): At ambient humidity below 80 % (no condensation)



■ HIGH VOLTAGE POWER SUPPLY C10940 SERIES 0.7 W output 1200 V / 0.6 mA

The C10940 series is a high voltage power supply module developed for compact size and high performance. This is designed to mount on a printed circuit making them suitable for use with a H12400 series Micro PMT assembly. Besides high performance and low power consumption, a variety of protective functions are also included.

Parameter		C10940-03	C10940-03-R2*	C10940-53	C10940-53-R2*	Unit	
Input voltage (VDD)			+5.0 ± 0.5				V
Input current ^①	with full load	Тур.	60				4
	with no load	Тур.	230				mA
Specification guaranteed output voltage range ^②		2	-200 to -1200 +200 to +1200			V	
Output current		Max.	0.6				mA
Line regulation ^{①③}		Тур.	±0.02				%
Load regulation ^①		Тур.	±0.01				%
Ripple / Noise (p-p) 13		Тур.	50				mV
Output voltage rise time (Rise time 0 %→99 %) ^{①③} 7		Тур.	120	300	120	300	ms
Temperature coefficient (1)3			±0.01				%/°C
Operating ambient temperature (1)3			0 to +50				°C
Weight			7.7				g
Dimensions (W \times H \times D)			15 × 18 × 15				mm
Protective functions		Units protected against reversed power input, reversed / excessive				_	
		controlling voltage input, continuous overloading / short circuit output					

- 1): At maximum output voltage
- $\begin{tabular}{ll} \hline @: The voltage from 0 V to $-$200 V/$+200 V can be output but all characteristics are not necessarily satisfied. \\ \hline \end{tabular}$
- 3: At maximum output current
- 4: No condensation
- * -R2 type: RS-485 control

Related **Products**



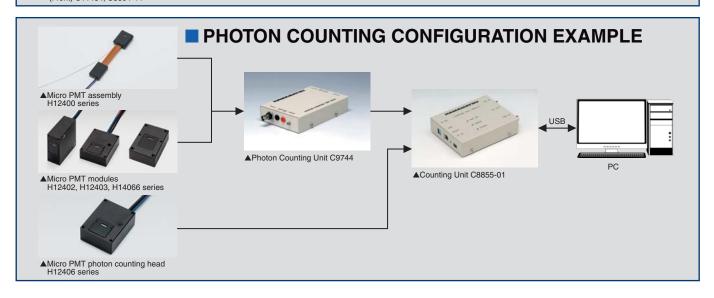
■ POWER SUPPLY FOR PMT MODULE C10709

The C10709 is a power supply unit designed to operate a PMT module. This unit supplies both drive voltage and control voltage, making it ideal for operating the H12402 series, H12403 series, H12404 series, H12405 series and H12406 series Micro PMT modules.

AMPLIFIER UNITS

These amplifier units convert the signal current input from a photomultiplier tube into a voltage output. Please select the desired type with a frequency range and current-to-voltage conversion factor that match your applications.

▲ (Rear) C7319, C9663, C6438 (Front) C11184, C5594-44



* 🗓 PMT is the registered trademark of Hamamatsu Photonics K.K. in Japan, U.S.A., EU, China and Republic of Korea.

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